	L#	Hits	Search Text	DBs
1	L2	14110	microlens\$4 or micro adj lens\$4 or array near3 lens\$4 or lenslet	EPO; JPO; DERW ENT; IBM_T DB
2	L3	30151 6	positive	EPO; JPO; DERW ENT; IBM_T DB
3	L4	292	2 and 3	EPO; JPO; DERW ENT; IBM_T DB
4	L 5	46913 6	bond\$ adj pad or scribe or recess\$4	EPO; JPO; DERW ENT; IBM_T DB
5	L6	7	4 and 5	EPO; JPO; DERW ENT; IBM_T DB
6	L7	15466 08	planar\$6 or level\$4 or flat or flatten\$6	EPO; JPO; DERW ENT; IBM_T DB
7	L8	48	4 and 7	EPO; JPO; DERW ENT; IBM_T DB
8	L 9		wafer or semiconductor or image or imager or imaging	EPO; JPO; DERW ENT; IBM_T DB
9	L10	184	4 and 9	EPO; JPO; DERW ENT; IBM_T DB

	L#	Hits	Search Text	DBs
10	L11	14448	positive near3 (resist or photoresist ot photo or photosensitiv\$6)	EPO; JPO; DERW ENT; IBM_T DB
11	L12	50	10 and 11	EPO; JPO; DERW ENT; IBM_T DB
12	L13	34	12 not (6 or 8)	EPO; JPO; DERW ENT; IBM_T DB
13	L14	2651	(microlens\$4 or micro adj lens\$4 or array near3 lens\$4 or lenslet).ti,ab.	USPA T; US-PG PUB
14	L15	54753 6	bond\$ adj pad or scribe or recess\$4	USPA T; US-PG PUB
15	L16	17816	positive near3 (resist or photoresist ot photo or photosensitiv\$6)	USPA T; US-PG PUB
16	L17	143	15 with 16	USPA T; US-PG PUB
17	L18	8	14 and 17	USPA T; US-PG PUB
18	L20	28398 8	(planar\$6 or level\$4 or flat or flatten\$6).ti,ab.	USPA T; US-PG PUB
19	L21	48501	positive.ti,ab.	USPA T; US-PG PUB
20	L22	6	14 and 20 and 21	USPA T; US-PG PUB

	L#	Hits	Search Text	DBs
21	L24	67941	(bond\$ adj pad or scribe or recess\$4).ti,ab.	USPA T; US-PG PUB
22	L25	32681 4	(wafer or semiconductor or image or imager or imaging).ti,ab.	USPA T; US-PG PUB
23	L26	20	14 and 24 and 25	USPA T; US-PG PUB
24	L27	325	438/69,71.ccls.	USPA T; US-PG PUB
25	L28	119	438/70.ccls.	USPA T; US-PG PUB
26	L29	29	14 and 28	USPA T; US-PG PUB